

SNV/U High Performances UV Microchip Series



KEY FEATURES

- 355 nm and 266 nm
- Repetition rate up to 30 kHz
- Ultrashort pulses down to 550 ps
- Multi-kW peak power
- Excellent beam quality
- · Efficient, air-cooled
- Sealed package, extremely long life

For generating high peak power ultraviolet pulses of a few hundred picoseconds, microchip lasers are economical, compact, and reliable. Micro-joule UV pulses are generated by harmonic conversion of the IR passively Q-switched Nd:YAG engine. Microchips are also easy to operate and service; controllers can be used with every laser head model and swapped within minutes while conserving constant performances. The SNV and SNU series are designed for high average power, delivering multi-kW peak power at repetition rates up to 30 kHz.

APPLICATIONS

- Semiconductor inspection
- Laser-induced fluorescence (LIF)
- Micro-dissection
- Organic compound marking and micromachining

- Biohazard detection
- Time resolved fluorescence
- Laser Induced Breakdown Spectroscopy (LIBS)
- Biophotonics



TECHNICAL SPECIFICATIONS

	SNV-05P-100	SNV-20F- 100 ⁽⁷⁾	SNV-40P-100	SNV-60P-100	SNU-02P-100	SNU-20F-100
Wavelength	355nm	355nm	355nm	355nm	266nm	266nm
Repetition Rate	>5kHz	>19kHz	>19kHz	>29kHz	>6kHz	>19kHz
Pulse duration (FWHM) (1)	<0.6ns	<0.6ns	<0.6ns	<0.6ns	<0.6ns	<0.6ns
Output power ⁽²⁾	>5mW	>10mW	>40mW	>58mW	>2mW	>10mW
Output energy	>0.5µJ	>0.5µJ	>2µJ	>2µJ	>0.3µJ	>0.5µJ
Peak Power	>0.7kW	0.7kW	> 5 kW	> 5 kW	>0.5kW	>0.7kW
Short term (10min) power stability ⁽³⁾	<±2%	<±2%	<±2%	<±2%	<±2%	<±2%
Long term (6 hrs) power stability ⁽³⁾	<±5%	<±5%	<±5%	<±5%	<±5%	<±5%
Beam profile Full angle divergence	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	See note (5)	See note (5)
Horizontal@1/e² Vertical@1/e²	8.5±2mrad 6±2mrad	11±2mrad 7±2mrad	11±2mrad 7±2mrad	11±2mrad 7±2mrad	11±2mrad <1.5mm ⁽⁶⁾	11.5±2mrad 0.65±0.25mrad
M ²⁽⁴⁾	<1.3	<1.3	<1.3	<1.3	<1.3	<1.4
Gaussian fit in far field	N/A	N/A	N/A	N/A	N/A	>85%
Polarization	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB
Package dimensions	180x55x36mm	186x60x36mm	186x60x36mm	186x60x36mm	180x55x36mm	210x60x36mm
Package weight	400g	500g	500g	500g	400g	500g
Options (table p3)	С	С	С	С	С	С
Options included	-	S	S	S	-	S

^{*} The specifications will be confirmed after the Beta phase only. For the moment, the specifications are preliminary, which means that the final laser parameters might be different than the current specifications.

⁽¹⁾ Measured with 1Ghz photodiode and 1GHz/10GS/s oscilloscope.

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(2) Measurement performed with an OPHIR thermal power sensor (OPHIR 3A-FS-SH)
(3) For temperature variation < ± 3°C and < 3°C/hour, stability is measured with calorimeter - detector band [DC, 2Hz]
(4) Mean average value M = √(XY), X and Y being respectively the major and minor axis of the ellipse
(5) Beam exhibits different profile in horizontal (Gaussian) and vertical ((sin x /x)² in far-field) plan

^{(6) 5%/95%} diameter, at 300mm from laser output (7) Contact factory for availability



COMPLEMENTARY INFORMATION & OPTIONS

Environment Parameters				
Operating Temperature Range	15-35°C			
Maximum Laser Head Baseplate Temperature	<50°C			
Maximum Power Consumption	<40W			
Laser Head Thermal Dissipation	<15W			
Storage Temperature	0-50°C			
Shock of 11ms according to IEC 68-2-27, non operating	25g			
Vibration 5Hz to 500Hz sinusoïdal according to IEC 68-2-6	2g			

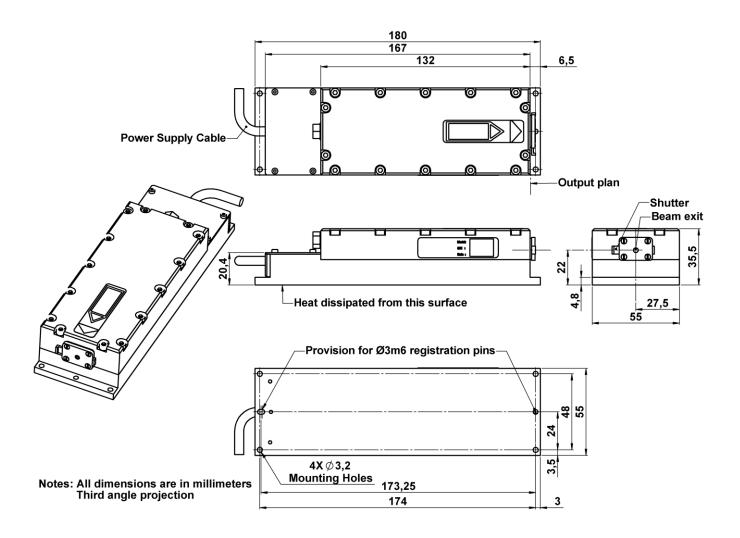
Certification						
Laser classification according to IEC 60825-1:2007	3B for SNV lasers 4 for SNU-02P and SNU-20F					
CDRH	Yes, if used with a -DR1 controller					
RoHS	Yes					

Options	
Collimation (C)	With collimated beam
Synchronization output (S)	TTL compatible output signal for synchronization/monitoring

Available Controller Types							
Model for the SNV-60-100 laser	Model for the other SNV and SNU lasers	Туре	Input Power	CDRH			
MLC-05A-DR1	MLC-03A-DR1	Desktop	100-240 V AC	Yes			
MLC-05A-MR1	MLC-03A-MR1	Module	12 V DC	No			
MLC-05A-BR1	MLC-03A-BR1	Board	12 V DC	No			

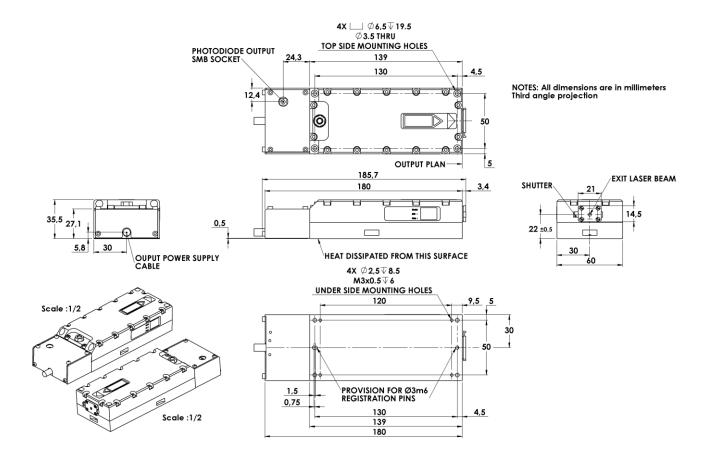


CDRH LASER HEAD MECHANICAL DRAWINGS: SNV-05P-100





CDRH LASER HEAD MECHANICAL DRAWINGS: SNV-20F-100, SNV-40P-100 & SNV-60P-100





CDRH LASER HEAD MECHANICAL DRAWINGS: SNU-02P-100

180 167 132 6,5 **Power Supply Cable** -Output plan Shutter Beam exit 35,5 Heat dissipated from this surface 27,5 55 Provision for Ø3m6 registration pins 48 55 3,5 **4X** ∅ **3,2** Mounting Holes 173,25 Notes: All dimensions are in millimeters Third angle projection 174 3



CDRH LASER HEAD MECHANICAL DRAWINGS: SNU-20F-100

4X ∟ Ø 6,5 ₹ 19.5 **Ø3.5 THRU** TOP SIDE MOUNTING HOLES 41 159 24,5 130 NOTES: All dimensions are in millimeters Third angle projection **o** 99 0 EXIT LASER BEAM PURGING VALVE **o o o** OUTPUT PLAN-2 H - H - A 35,5 _{27,1,} 22 ±0,5 OUPUT POWER SUPPLY CABLE HEAT DISSIPATED FROM THIS SURFACE 30 5,4 0,5 180 20 200 8,2 202,1 4X Ø2,5**∀8.**5 $\mathbf{M3x0.5} \mathbf{\mathbf{\mathbf{7}}6}$ UNDER SIDE MOUNTING HOLES 120 5 30 50 1,5 PROVISION FOR Ø3m6 0,75 REGISTRATION PINS 1,5 130 4,5 139 180 (20)